SiUD406ED

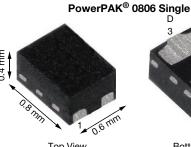
www.vishay.com

Vishay Siliconix

RoHS

COMPLIANT

HALOGEN FREE





Bottom View

Top View Marking code: J

PRODUCT SUMMARY					
V _{DS} (V)	30				
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	1.46				
$R_{DS(on)}$ max. (Ω) at V_{GS} = 2.5 V	1.66				
$R_{DS(on)}$ max. (Ω) at V_GS = 1.8 V	1.85				
Q _g typ. (nC)	0.4				
I _D (A)	0.5 ^{a, f}				
Configuration	Single				

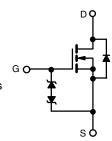
FEATURES

N-Channel 30 V (D-S) MOSFET

- TrenchFET[®] power MOSFET
- Ultra small 0.8 mm x 0.6 mm outline
- Ultra thin 0.4 mm max. height
- Typical ESD protection 1000 V (HBM)
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Load switch
- · High speed switching
- DC/DC converters
- · Battery-operated and mobile devices



N-Channel MOSFET

ODDEDING INFORMATION

Package	PowerPAK 0806			
Lead (Pb)-free and halogen-free	SiUD406ED-T1-GE3			

Note

The lead finish is NiPdAu and classed as E4 finish

PARAMETER		SYMBOL LIMIT		UNIT	
Drain-source voltage		V _{DS}	30		
Gate-source voltage		V _{GS}	± 8	V	
	T _A = 25 °C		0.5 ^{a, f}		
Continuous ducia compaty (T. 150 °C)	T _A = 70 °C		0.5 ^a		
Continuous drain current /T _J = 150 °C)	T _A = 25 °C	I _D	0.37 ^b		
	T _A = 70 °C		0.29 ^b	А	
Pulsed drain current (t = 100 μs)		I _{DM}	0.8		
	T _A = 25 °C		0.5 ^{a, f}		
Continuous source-drain diode current	T _A = 25 °C	I _S	0.31 ^b		
	T _A = 25 °C		1.25 ^a		
	T _A = 70 °C		0.8 ^a		
Maximum power dissipation	T _A = 25 °C	P _D	0.37 ^b	W	
	T _A = 70 °C	1	0.24 ^b		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) °			260	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT	
Maximum junction-to-ambient a, d	t ≤ 5 s	R _{thJA}	80	100	°C/W	
Maximum junction-to-ambient b, e	t ≤ 5 s	R _{thJA}	265	335	C/W	

Notes

Surface mounted on 1" x 1" FR4 board with full copper, t = 5 s Surface mounted on 1" x 1" FR4 board with minimum copper, t = 5 s а.

b.

Refer to IPC / JEDEC[®] (J-STD-020), no manual or hand soldering Maximum under steady state conditions is 135 °C/W Maximum under steady state conditions is 400 °C/W c.

d.

e. f.

Package limited

S20-0847-Rev. B, 26-Oct-2020

1

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

www.vishay.com

SiUD406ED

Vishay Siliconix

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Static						<u> </u>
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	30	-	-	V
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$	L 050 A	-	28	-	
V _{GS(th)} temperature coefficient	$\Delta V_{GS(th)}/T_J$	I _D = 250 μA	-	-1.5	-	mV/°C
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.4	-	1.1	V
		$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$	-	-	± 0.5	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 8 V$	-	-	10	1.
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	μA
Zero gate voltage drain current	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	-	-	10	1
On-state drain current ^a	I _{D(on)}	$V_{DS}\!\geq\!5$ V, V_{GS} = 4.5 V	0.5	-	-	А
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 0.2 \text{ A}$	-	1.17	1.46	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 0.1 \text{ A}$	-	1.24	1.66	Ω
		$V_{GS} = 1.8 \text{ V}, \text{ I}_{D} = 0.1 \text{ A}$	-	1.37	1.85	
Forward transconductance ^a	9 _{fs}	$V_{DS} = 5 \text{ V}, \text{ I}_{D} = 0.4 \text{ A}$	-	1.2	-	S
Dynamic ^b				•		•
Input capacitance	Ciss		-	17	-	pF
Output capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz	-	5	-	
Reverse transfer capacitance	C _{rss}		-	2.5	-	
Total gate charge	Qg	V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 0.2 A	-	0.4	0.6	
Gate-source charge	Q _{gs}	V _{DS} = 15 V, V _{GS} = 4.5 V, I _D = 0.2 A	-	0.04	-	nC
Gate-drain charge	Q _{gd}	$v_{DS} = 15 v, v_{GS} = 4.5 v, I_D = 0.2 A$	-	0.1	-	
Gate resistance	Rg	f = 1 MHz	3	15	30	Ω
Turn-on delay time	t _{d(on)}		-	5	10	-
Rise time	t _r	V_{DD} = 15 V, R_L = 75 Ω , $I_D \cong 0.2$ A,	-	5	10	
Turn-off delay time	t _{d(off)}	V_{GEN} = 4.5 V, R_g = 1 Ω	-	20	40	
Fall time	t _f		-	5	10	
Turn-on delay time	t _{d(on)}		-	5	10	ns
Rise time	tr	V_{DD} = 15 V, R_L = 75 Ω , $I_D \cong 0.2$ A,	-	5	10	-
Turn-off delay time	t _{d(off)}	V_{GEN} = 8 V, R_g = 1 Ω	-	7	15	
Fall time	t _f		-	5	10	
Drain-Source Body Diode Characteristi	cs					
Continuous source-drain diode current	I _S	T _A = 25 °C	-	-	0.5 ^c	
Pulse diode forward current	I _{SM}		-	-	0.8	A
Body diode voltage	V _{SD}	$I_{\rm S}$ = 0.2 A, $V_{\rm GS}$ = 0 V	-	0.88	1.2	V
Body diode reverse recovery time	t _{rr}		-	10	20	ns
Body diode reverse recovery charge	Q _{rr}	I _F = 0.2 A, di/dt = 100 A/μs,	-	3	6	nC
Reverse recovery fall time	ta	$T_{\rm J} = 25 \ ^{\circ}{\rm C}$	-	5	-	
Reverse recovery rise time	t _b		-	5	-	ns

Notes

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Surface mounted on 1" x 1" FR4 board with full copper, t = 5 s

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

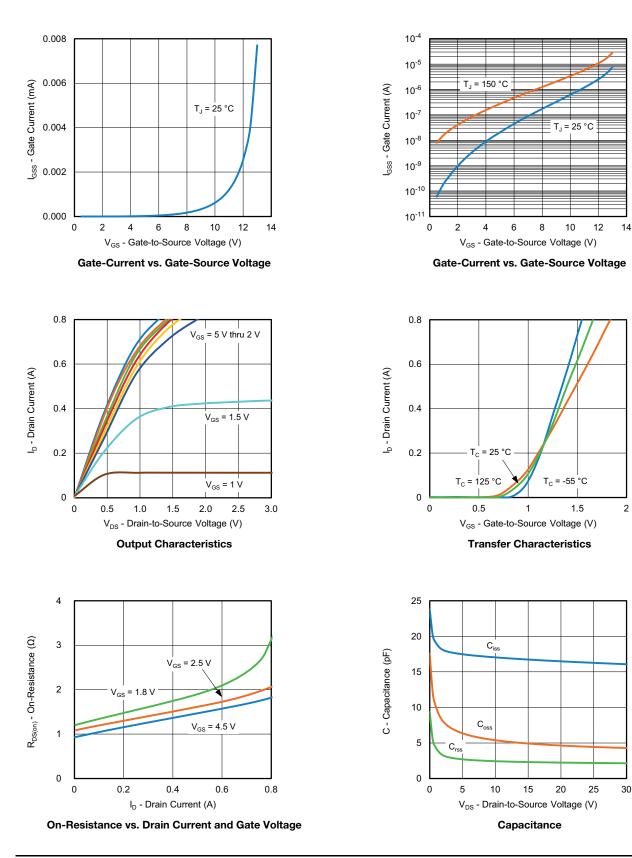
Document Number: 75906



SiUD406ED

Vishay Siliconix

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



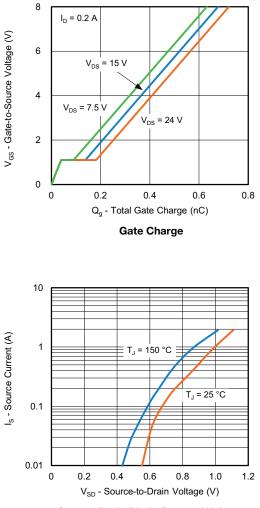
3

Document Number: 75906

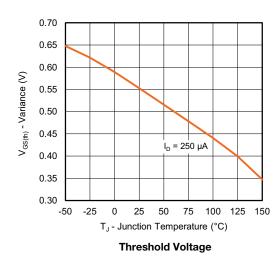
For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

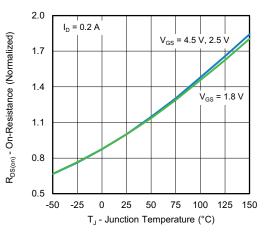


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

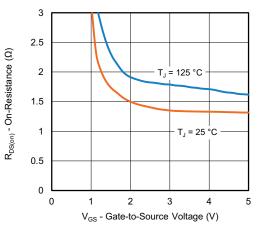


Source-Drain Diode Forward Voltage

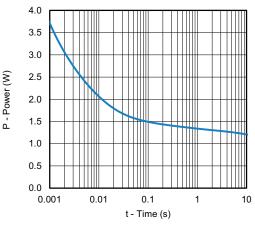




On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient

S20-0847-Rev. B, 26-Oct-2020

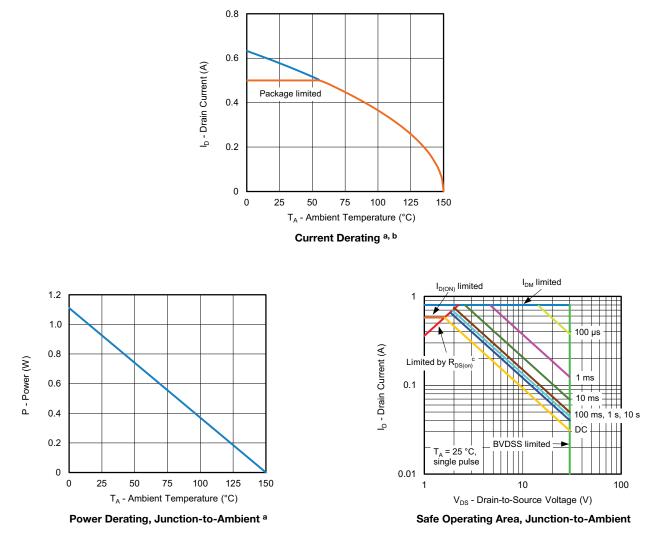
4

Document Number: 75906

For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

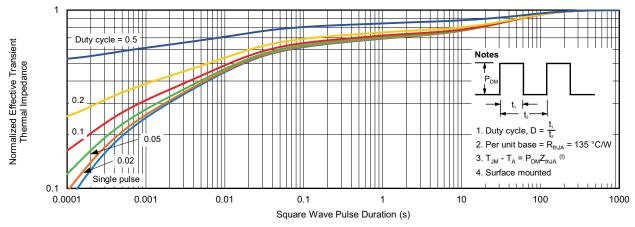


Notes

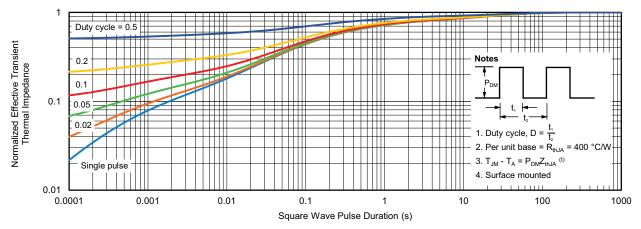
- a. When mounted on 1" x 1" FR4 with full copper
- b. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-ambient thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit
- c. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient (on 1" x 1" FR4 board with maximum copper)



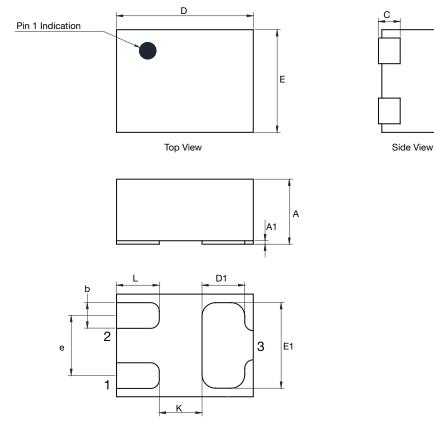
Normalized Thermal Transient Impedance, Junction-to-Ambient (on 1" x 1" FR4 board with minimum copper)

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75906.

S20-0847-Rev. B, 26-Oct-2020	6	Document Number: 75906
For techn	nical questions, contact: pmostechsupport	@vishay.com
		DESCRIBED HEREIN AND THIS DOCUMENT
ARE SUBJECT TO SPI	ECIFIC DISCLAIMERS, SET FORTH AT WW	vw.vishav.com/doc?91000



Case Outline for PowerPAK 0.8 mm x 0.6 mm



Bottom View

	MILLIMETERS				INCHES	
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
А	0.350	0.380	0.400	0.0138	0.0150	0.0157
A1	0	-	0.020	0	-	0.0008
b	0.120	0.150	0.180	0.0047	0.0059	0.0071
С	0.119	0.127	0.135	0.0047	0.0050	0.0053
D	0.750	0.800	0.850	0.0295	0.0315	0.0335
D1	0.200	0.250	0.300	0.0078	0.0098	0.0118
E	0.550	0.600	0.650	0.0217	0.0236	0.0256
E1	0.450	0.500	0.550	0.0177	0.0197	0.0217
е	0.300	0.350	0.400	0.0118	0.0138	0.0158
К	0.150	0.250	0.350	0.0058	0.0098	0.0138
L	0.200	0.250	0.300	0.0078	0.0098	0.0118
ECN: C13-1574-R DWG: 6020	Rev. A, 23-Dec-13					

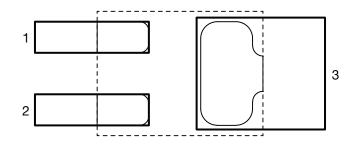
Revision: 23-Dec-13

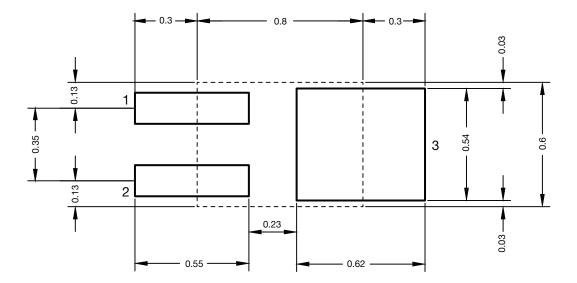
1





Recommended Land Pattern PowerPAK® 0806







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.